Product data sheet

1. General description

Planar passivated high commutation three quadrant triac in a TO92 plastic package intended for use in circuits where high static and dynamic dV/dt and high dl/dt can occur. This series triac will commutate the full rated RMS current at the maximum rated junction temperature without the aid of a snubber.

2. Features and benefits

- · 3Q technology for improved noise immunity
- High blocking voltage capability
- · High commutation capability with maximum false trigger immunity
- High immunity to false turn-on by dV/dt
- · Less sensitive gate for high noise immunity
- Planar passivated for voltage ruggedness and reliability
- · Triggering in three quadrants only

3. Applications

- General purpose motor control circuits
- Home appliances
- Solenoid drivers

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Values	Unit				
Absolute	Absolute maximum rating							
V_{DRM}	repetitive peak off-state voltage		800	V				
I _{T(RMS)}	RMS on-state current	full sine wave; Fig. 1; Fig. 2; Fig. 3	3	Α				
I _{TSM}	non-repetitive peak on- state current	full sine wave; $t_p = 16.7 \text{ ms}$; $T_{j(init)} = 25 ^{\circ}\text{C}$	30	А				
	State current	full sine wave; t_p = 20 ms; $T_{j(init)}$ = 25 °C Fig. 4; Fig. 5	27	A				
T _j	junction temperature		150	°C				

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics			,		•
I_{GT}	gate trigger current	$V_D = 12 \text{ V; } I_T = 0.1 \text{ A; } T2 + G + T_j = 25 \text{ °C; } Fig. 7$	-	-	30	mA
		$V_D = 12 \text{ V; } I_T = 0.1 \text{ A; } T2 + G-$ $T_j = 25 \text{ °C; } Fig. 7$	-	-	30	mA
		$V_D = 12 \text{ V; } I_T = 0.1 \text{ A; T2- G-} $ $T_j = 25 \text{ °C; } Fig. 7$	-	-	30	mA
V_T	on-state voltage	I _T = 5 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.4	1.7	V
Dynamic	characteristics				'	
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T_j = 125 °C; (V_{DM} = 67% of V_{DRM}); exponential waveform; gate open circuit	2000	-	-	V/µs
		V_{DM} = 536 V; T_j = 150 °C; (V_{DM} = 67% of V_{DRM}); exponential waveform; gate open circuit	1500	-	-	V/µs
dI _{com} /dt	rate of change of commutating current	V_D = 400 V; T_j = 150 °C; $I_{T(RMS)}$ = 3 A; dV_{com}/dt = 20 V/ μ s; (snubberless condition); gate open circuit	5	-	-	A/ms

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	T2	main terminal 2		N.I.
2	G	gate		T2—T1
3	T1	main terminal 1	() () () () () () () () () () () () () (sym051

6. Ordering information

Table 3. Ordering information

Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date	
BTA203-800CT	TO92	BTA203-800CTEP	Bulk	1000	SOT54	14-Nov-2013	
BTA203-800CT	TO92	BTA203-800CTQP	Reel	2000	SOT54 wide pitch	14-Nov-2013	
BTA203-800CT/L01	TO92	BTA203-800CT/L01EP	Bulk	500	SOT54/L01	14-Nov-2013	

7. Marking

Table 4. Marking codes

Type number	Marking codes
BTA203-800CT	203-8C

8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{DRM}	repetitive peak off-state voltage		800	V
$I_{T(RMS)}$	RMS on-state current	full sine wave; Fig. 1; Fig. 2; Fig. 3	3	Α
I _{TSM}	non-repetitive peak on-	full sine wave; $t_p = 16.7 \text{ ms}$; $T_{j(init)} = 25 \text{ °C}$	30	А
	state current	full sine wave; t_p = 20 ms; $T_{j(init)}$ = 25 °C; Fig. 4; Fig. 5	27	А
l ² t	I ² t for fusing	t _p = 10 ms; sine wave	3.7	A ² s
dl _⊤ /dt	rate of rise of on-state current	I _G = 60 mA	100	A/µs
I _{GM}	peak gate current		2	А
P_GM	peak gate power		5	W
$P_{G(AV)}$	average gate power	over any 20 ms period	0.3	W
T _{stg}	storage temperature		-40 to 150	°C
T _j	junction temperature		150	°C

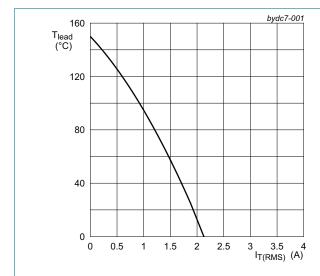
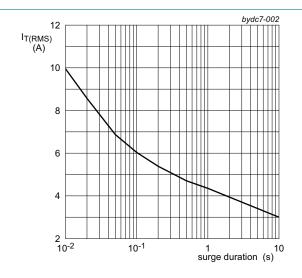
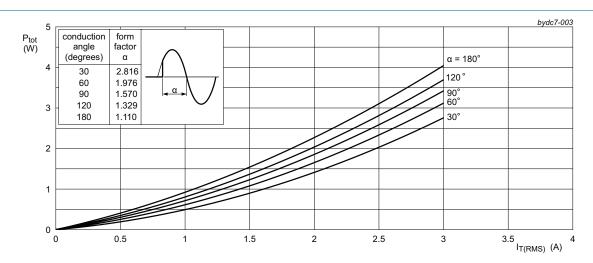


Fig. 1. RMS on-state current as a function of lead temperature; maximum values



f = 50Hz

Fig. 2. RMS on-state current as a function of surge duration; maximum values



 α = conduction angle

a = form factor = $I_{T(RMS)}$ / $I_{T(AV)}$

Fig. 3. Total power dissipation as a function of RMS on-state current; maximum values

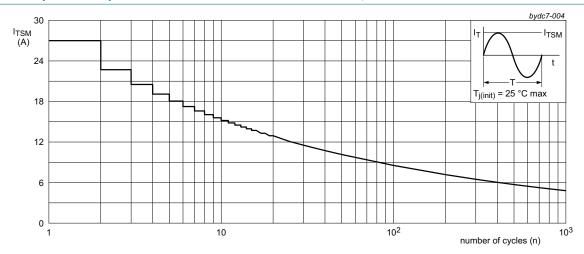
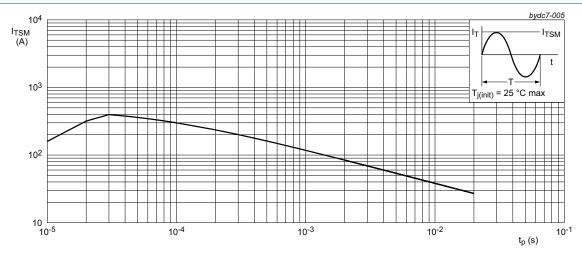


Fig. 4. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values



 $t_{D} \le 20 \text{ ms}$; (1) dl_T/dt limit

BTA203-800CT

Total power dissipation as a function of RMS on-state current; maximum values

9. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-lead)}}$	thermal resistance from junction to lead	Fig. 6	-	-	60	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air	-	150	-	K/W

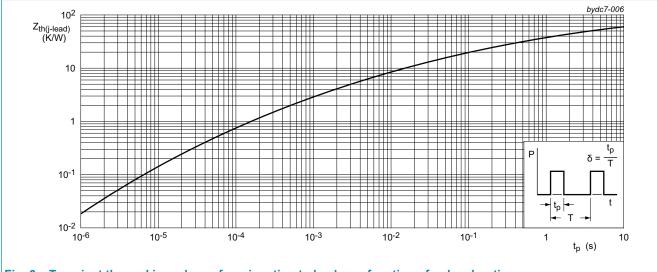
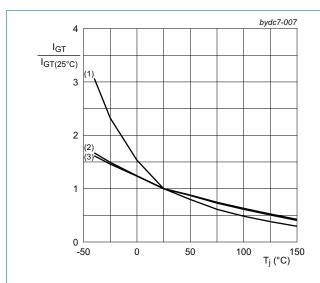


Fig. 6. Transient thermal impedance from junction to lead as a function of pulse duration

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics		,			
I _{GT}	gate trigger current	$V_D = 12 \text{ V; } I_T = 0.1 \text{ A; } T2+ \text{ G+;}$ $T_j = 25 \text{ °C; } Fig. 7$	-	-	30	mA
		$V_D = 12 \text{ V; } I_T = 0.1 \text{ A; } T2 + \text{ G-;} $ $T_j = 25 \text{ °C; } Fig. 7$	-	-	30	mA
		$V_D = 12 \text{ V; } I_T = 0.1 \text{ A; T2- G-;}$ $T_j = 25 \text{ °C; } Fig. 7$	-	-	30	mA
l _L	latching current	$V_D = 12 \text{ V; } I_T = 0.1 \text{ A; } T2+ \text{ G+;} $ $T_j = 25 \text{ °C; } \underline{\text{Fig. 8}}$	-	-	30	mA
		$V_D = 12 \text{ V; } I_T = 0.1 \text{ A; } T2 + G-;$ $T_j = 25 \text{ °C; } Fig. 8$	-	-	60	mA
		$V_D = 12 \text{ V; } I_T = 0.1 \text{ A; T2- G-;}$ $T_j = 25 \text{ °C; } Fig. 8$	-	-	30	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	-	30	mA
V_T	on-state voltage	I _T = 5 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.4	1.7	V
V_{GT}	gate trigger voltage	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T_j = 25 \text{ °C};$ Fig. 11	-	0.7	1	V
		V _D = 400 V; I _T = 0.1 A; T _j = 150 °C	0.25	0.45	-	V
I _D	off-state current	V _D = 800 V; T _j = 25 °C	-	-	10	μA
		V _D = 800 V; T _j = 150 °C	-	-	0.5	mA
Dynamic o	characteristics				'	1
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T_j = 125 °C; (V_{DM} = 67% of V_{DRM}); exponential waveform; gate open circuit	2000	-	-	V/µs
		V_{DM} = 536 V; T_{j} = 150 °C; (V_{DM} = 67% of V_{DRM}); exponential waveform; gate open circuit	1500	-	-	V/µs
dI _{com} /dt	rate of change of commutating current	$V_D = 400 \text{ V}; T_j = 150 \text{ °C}; I_{T(RMS)} = 3 \text{ A};$ $dV_{com}/dt = 20 \text{ V/}\mu\text{s}; \text{ (snubberless condition)}; gate open circuit$	5	-	-	A/ms



- (1) T2- G-
- (2) T2+ G-

0 -50

Fig. 7. Normalized gate trigger current as a function of

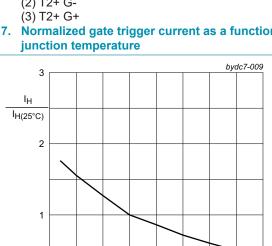


Fig. 9. Normalized holding current as a function of junction temperature

50

0

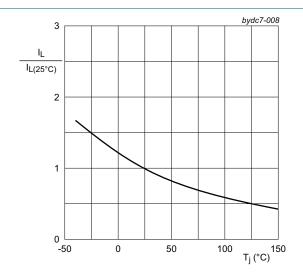
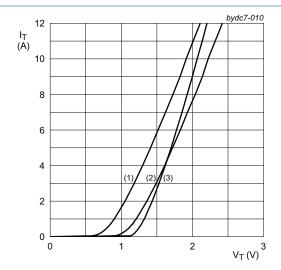


Fig. 8. Normalized latching current as a function of junction temperature



 V_o = 0.787 V; R_s = 0.2133 Ω

(1) T_j = 150 °C; typical values (2) T_j = 150 °C; maximum values

(3) T_i = 25 °C; maximum values

Fig. 10. On-state current as a function of on-state voltage

T_j (°C) 150

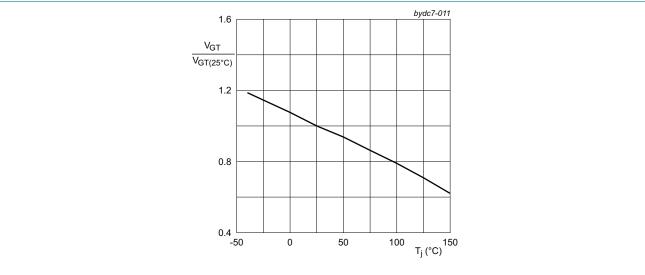
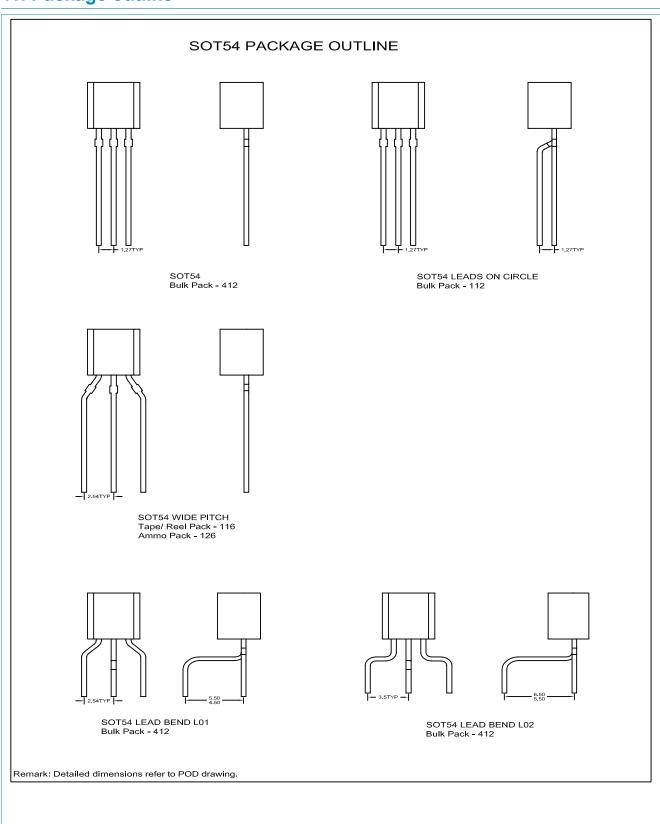


Fig. 11. Normalized gate trigger voltage as a function of junction temperature

11. Package outline



12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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